Marcel A Verheijen

List of Publications by Year in Descending Order

252 papers	9,931 citations	55 h-index	92 g-index
278 ext. papers	11,192 ext. citations	7.6 avg, IF	6.1 L-index

#	Paper	IF	Citations
252	Continuous-Flow Sunlight-Powered CO2 Methanation Catalyzed by Al2O3-Supported Plasmonic Ru Nanorods. *Catalysts*, **2022**, 12, 126	4	1
251	Comparing the Performance of Supported Ru Nanocatalysts Prepared by Chemical Reduction of RuCl3 and Thermal Decomposition of Ru3(CO)12 in the Sunlight-Powered Sabatier Reaction. *Catalysts*, **2022**, 12, 284	4	0
250	Controlling transition metal atomic ordering in two-dimensional Mo1 W x S2 alloys. *2D Materials*, **2022**, 9, 025016	5.9	0
249	Thickness and Morphology Dependent Electrical Properties of ALD-Synthesized MoS 2 FETs. *Advanced Electronic Materials*, **2022**, 8, 2100781	6.4	0
248	Enhanced Self-Assembled Monolayer Surface Coverage by ALD NiO in p-i-n Perovskite Solar Cells.. *ACS Applied Materials & Interfaces*, **2021**,	9.5	9
247	Excellent surface passivation of germanium by a-Si:H/Al2O3 stacks. *Journal of Applied Physics*, **2021**, 130, 135303	2.5	4
246	Parity-preserving and magnetic field-resilient superconductivity in InSb nanowires with Sn shells. *Science*, **2021**, 372, 508-511	33.3	13
245	Improved Pd/CeO Catalysts for Low-Temperature NO Reduction: Activation of CeO Lattice Oxygen by Fe Doping. *ACS Catalysis*, **2021**, 11, 5614-5627	13.1	10
244	Unveiling Planar Defects in Hexagonal Group IV Materials. *Nano Letters*, **2021**, 21, 3619-3625	11.5	3
243	Impact of Ions on Film Conformality and Crystallinity during Plasma-Assisted Atomic Layer Deposition of TiO. *Chemistry of Materials*, **2021**, 33, 5002-5009	9.6	5
242	On the Contact Optimization of ALD-Based MoS FETs: Correlation of Processing Conditions and Interface Chemistry with Device Electrical Performance. *ACS Applied Electronic Materials*, **2021**, 3, 3185-3199	4	2
241	Universal Platform for Scalable Semiconductor-Superconductor Nanowire Networks. *Advanced Functional Materials*, **2021**, 31, 2103062	15.6	1
240	Prismatic Ge-rich inclusions in the hexagonal SiGe shell of GaP-Si-SiGe nanowires by controlled faceting. *Nanoscale*, **2021**, 13, 9436-9445	7.7	
239	Surface passivation of germanium by atomic layer deposited Al2O3 nanolayers. *Journal of Materials Research*, **2021**, 36, 571-581	2.5	8
238	Phase separation of VO2 and SiO2 on SiO2-Coated float glass yields robust thermochromic coating with unrivalled optical properties. *Solar Energy Materials and Solar Cells*, **2021**, 230, 111238	6.4	2
237	Novel microreactor and generic model catalyst platform for the study of fast temperature pulsed operation CO oxidation rate enhancement on Pt. *Chemical Engineering Journal*, **2021**, 425, 131559	14.7	2
236	Atomic-layer-deposited Al-doped zinc oxide as a passivating conductive contacting layer for n+-doped surfaces in silicon solar cells. *Solar Energy Materials and Solar Cells*, **2021**, 233, 111386	6.4	10

235	Conformal Growth of Nanometer-Thick Transition Metal Dichalcogenide TiS -NbS Heterostructures over 3D Substrates by Atomic Layer Deposition: Implications for Device Fabrication. *ACS Applied Nano Materials*, **2021**, 4, 514-521	5.6	3
234	Probing Lattice Dynamics and Electronic Resonances in Hexagonal Ge and SiGe Alloys in Nanowires by Raman Spectroscopy. *ACS Nano*, **2020**, 14, 6845-6856	16.7	11
233	Ballistic Phonons in Ultrathin Nanowires. *Nano Letters*, **2020**, 20, 2703-2709	11.5	17
232	Extraction of Dzyaloshinskii-Moriya interaction from propagating spin waves. *Physical Review B*, **2020**, 101,	3.3	9
231	Large area, patterned growth of 2D MoS and lateral MoS-WS heterostructures for nano- and opto-electronic applications. *Nanotechnology*, **2020**, 31, 255603	3.4	28
230	Atomic layer deposition of Nb-doped TiO2: Dopant incorporation and effect of annealing. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **2020**, 38, 022408	2.9	5
229	Kinetic Control of Morphology and Composition in Ge/GeSn Core/Shell Nanowires. *ACS Nano*, **2020**, 14, 2445-2455	16.7	12
228	Editorial Expression of Concern: Quantized Majorana conductance. *Nature*, **2020**, 581, E4	50.4	6
227	Area-Selective Atomic Layer Deposition of Two-Dimensional WS Nanolayers **2020**, 2, 511-518		24
226	Direct-bandgap emission from hexagonal Ge and SiGe alloys. *Nature*, **2020**, 580, 205-209	50.4	124
225	In-plane selective area InSb-Al nanowire quantum networks. *Communications Physics*, **2020**, 3,	5.4	18
224	Full characterization and modeling of graded interfaces in a high lattice-mismatch axial nanowire heterostructure. *Physical Review Materials*, **2020**, 4,	3.2	2
223	Precise ion energy control with tailored waveform biasing for atomic scale processing. *Journal of Applied Physics*, **2020**, 128, 213301	2.5	5
222	Probing the Origin and Suppression of Vertically Oriented Nanostructures of 2D WS Layers. *ACS Applied Materials & Interfaces*, **2020**, 12, 3873-3885	9.5	14
221	Hard Superconducting Gap and Diffusion-Induced Superconductors in Ge-Si Nanowires. *Nano Letters*, **2020**, 20, 122-130	11.5	10
220	Atomic layer deposition of ruthenium using an ABC-type process: Role of oxygen exposure during nucleation. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **2020**, 38, 062402	2.9	6
219	Collective photothermal effect of Al2O3-supported spheroidal plasmonic Ru nanoparticle catalysts in the sunlight-powered Sabatier reaction. *ChemCatChem*, **2020**, 12, 5618-5622	5.2	10
218	Area-Selective Atomic Layer Deposition of TiN Using Aromatic Inhibitor Molecules for Metal/Dielectric Selectivity. *Chemistry of Materials*, **2020**, 32, 7788-7795	9.6	21

217	Synthesis of edge-enriched WS2 on high surface area WS2 framework by atomic layer deposition for electrocatalytic hydrogen evolution reaction. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **2020**, 38, 062201	2.9	2
216	Atomic Layer Deposition of Al-Doped MoS: Synthesizing a p-type 2D Semiconductor with Tunable Carrier Density. *ACS Applied Nano Materials*, **2020**, 3, 10200-10208	5.6	7
215	Understanding the Film Formation Kinetics of Sequential Deposited Narrow-Bandgap PbSn Hybrid Perovskite Films. *Advanced Energy Materials*, **2020**, 10, 2000566	21.8	18
214	Plasma-Assisted ALD of Highly Conductive HfNx: On the Effect of Energetic Ions on Film Microstructure. *Plasma Chemistry and Plasma Processing*, **2020**, 40, 697-712	3.6	6
213	Strain engineering in Ge/GeSn core/shell nanowires. *Applied Physics Letters*, **2019**, 115, 113102	3.4	14
212	21.6%-Efficient Monolithic Perovskite/Cu(In,Ga)Se2 Tandem Solar Cells with Thin Conformal Hole Transport Layers for Integration on Rough Bottom Cell Surfaces. *ACS Energy Letters*, **2019**, 4, 583-590	20.1	106
211	Area-Selective Atomic Layer Deposition of ZnO by Area Activation Using Electron Beam-Induced Deposition. *Chemistry of Materials*, **2019**, 31, 1250-1257	9.6	43
210	Area-Selective Deposition of Ruthenium by Combining Atomic Layer Deposition and Selective Etching. *Chemistry of Materials*, **2019**, 31, 3878-3882	9.6	46
209	Phonon Engineering in Twinning Superlattice Nanowires. *Nano Letters*, **2019**, 19, 4702-4711	11.5	19
208	Edge-Site Nanoengineering of WS by Low-Temperature Plasma-Enhanced Atomic Layer Deposition for Electrocatalytic Hydrogen Evolution. *Chemistry of Materials*, **2019**, 31, 5104-5115	9.6	35
207	Boosting the Performance of WO3/n-Si Heterostructures for Photoelectrochemical Water Splitting: from the Role of Si to Interface Engineering. *Advanced Energy Materials*, **2019**, 9, 1900940	21.8	28
206	Electrochemistry of Sputtered Hematite Photoanodes: A Comparison of Metallic DC versus Reactive RF Sputtering. *ACS Omega*, **2019**, 4, 9262-9270	3.9	4
205	High Mobility Stemless InSb Nanowires. *Nano Letters*, **2019**, 19, 3575-3582	11.5	18
204	Sunlight-Fueled, Low-Temperature Ru-Catalyzed Conversion of CO and H to CH with a High Photon-to-Methane Efficiency. *ACS Omega*, **2019**, 4, 7369-7377	3.9	18
203	Hexagonal silicon grown from higher order silanes. *Nanotechnology*, **2019**, 30, 295602	3.4	6
202	Transition in layer structure of atomic/molecular layer deposited ZnO-zincone multilayers. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **2019**, 37, 040602	2.9	9
201	Low-Temperature Phase-Controlled Synthesis of Titanium Di- and Tri-sulfide by Atomic Layer Deposition. *Chemistry of Materials*, **2019**, 31, 9354-9362	9.6	15
200	Selective-area chemical beam epitaxy of in-plane InAs one-dimensional channels grown on InP(001), InP(111)B, and InP(011) surfaces. *Physical Review Materials*, **2019**, 3,	3.2	26

199	Bottom-Up Grown 2D InSb Nanostructures. *Advanced Materials*, **2019**, 31, e1808181	24	16
198	Polarized Raman spectroscopy to elucidate the texture of synthesized MoS. *Nanoscale*, **2019**, 11, 22860-22870	7.7	8
197	Plasma-assisted atomic layer deposition of nickel oxide as hole transport layer for hybrid perovskite solar cells. *Journal of Materials Chemistry C*, **2019**, 7, 12532-12543	7.1	40
196	Chemical Analysis of the Interface between Hybrid Organic-Inorganic Perovskite and Atomic Layer Deposited AlO. *ACS Applied Materials & Interfaces*, **2019**, 11, 5526-5535	9.5	28
195	Low-temperature plasma-enhanced atomic layer deposition of 2-D MoS: large area, thickness control and tuneable morphology. *Nanoscale*, **2018**, 10, 8615-8627	7.7	63
194	Low resistivity HfNx grown by plasma-assisted ALD with external rf substrate biasing. *Journal of Materials Chemistry C*, **2018**, 6, 3917-3926	7.1	25
193	Dopant Distribution in Atomic Layer Deposited ZnO:Al Films Visualized by Transmission Electron Microscopy and Atom Probe Tomography. *Chemistry of Materials*, **2018**, 30, 1209-1217	9.6	18
192	Shape and structural motifs control of MgTi bimetallic nanoparticles using hydrogen and methane as trace impurities. *Nanoscale*, **2018**, 10, 1297-1307	7.7	4
191	Efficient Green Emission from Wurtzite Al InP Nanowires. *Nano Letters*, **2018**, 18, 3543-3549	11.5	14
190	Surface Fluorination of ALD TiO2 Electron Transport Layer for Efficient Planar Perovskite Solar Cells. *Advanced Materials Interfaces*, **2018**, 5, 1701456	4.6	20
189	Bottom-up meets top-down: tailored raspberry-like FeO-Pt nanocrystal superlattices. *Nanoscale*, **2018**, 10, 5859-5863	7.7	3
188	Quantized Majorana conductance. *Nature*, **2018**, 556, 74-79	50.4	382
187	Tuning Material Properties of Oxides and Nitrides by Substrate Biasing during Plasma-Enhanced Atomic Layer Deposition on Planar and 3D Substrate Topographies. *ACS Applied Materials & Interfaces*, **2018**, 10, 13158-13180	9.5	59
186	Critical strain for Sn incorporation into spontaneously graded Ge/GeSn core/shell nanowires. *Nanoscale*, **2018**, 10, 7250-7256	7.7	24
185	Flow Cell Coupled Dynamic Light Scattering for Real-Time Monitoring of Nanoparticle Size during Liquid Phase Bottom-Up Synthesis. *Applied Sciences (Switzerland)*, **2018**, 8, 108	2.6	4
184	Low-Temperature Plasma-Assisted Atomic-Layer-Deposited SnO as an Electron Transport Layer in Planar Perovskite Solar Cells. *ACS Applied Materials & Interfaces*, **2018**, 10, 30367-30378	9.5	59
183	Spin-Orbit Interaction and Induced Superconductivity in a One-Dimensional Hole Gas. *Nano Letters*, **2018**, 18, 6483-6488	11.5	14
182	Isotropic Atomic Layer Etching of ZnO Using Acetylacetone and O Plasma. *ACS Applied Materials & Interfaces*, **2018**, 10, 38588-38595	9.5	21

181	Qualification of an Ultrasonic Instrument for Real-Time Monitoring of Size and Concentration of Nanoparticles during Liquid Phase Bottom-Up Synthesis. *Applied Sciences (Switzerland)*, **2018**, 8, 1064	2.6	1
180	Physical and Chemical Defects in WO3 Thin Films and Their Impact on Photoelectrochemical Water Splitting. *ACS Applied Energy Materials*, **2018**, 1, 5887-5895	6.1	33
179	Atomic-layer deposited Nb2O5 as transparent passivating electron contact for c-Si solar cells. *Solar Energy Materials and Solar Cells*, **2018**, 184, 98-104	6.4	41
178	Twofold origin of strain-induced bending in core-shell nanowires: the GaP/InGaP case. *Nanotechnology*, **2018**, 29, 315703	3.4	9
177	Decoupling high surface recombination velocity and epitaxial growth for silicon passivation layers on crystalline silicon. *Journal Physics D: Applied Physics*, **2017**, 50, 065305	3	4
176	Towards the implementation of atomic layer deposited In2O3:H in silicon heterojunction solar cells. *Solar Energy Materials and Solar Cells*, **2017**, 163, 43-50	6.4	22
175	Plasma-assisted atomic layer deposition of conformal Pt films in high aspect ratio trenches. *Journal of Chemical Physics*, **2017**, 146, 052818	3.9	15
174	Atomic layer deposition of HfO2 using HfCp(NMe2)3 and O2 plasma. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **2017**, 35, 01B130	2.9	19
173	Uniform Atomic Layer Deposition of AlO on Graphene by Reversible Hydrogen Plasma Functionalization. *Chemistry of Materials*, **2017**, 29, 2090-2100	9.6	42
172	Plasma-assisted atomic layer deposition of HfNx: Tailoring the film properties by the plasma gas composition. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **2017**, 35, 01B129	2.9	8
171	Boosting Hole Mobility in Coherently Strained [110]-Oriented Ge-Si Core-Shell Nanowires. *Nano Letters*, **2017**, 17, 2259-2264	11.5	36
170	Atomic layer deposition for perovskite solar cells: research status, opportunities and challenges. *Sustainable Energy and Fuels*, **2017**, 1, 30-55	5.8	114
169	Growth and Optical Properties of Direct Band Gap Ge/GeSn Core/Shell Nanowire Arrays. *Nano Letters*, **2017**, 17, 1538-1544	11.5	59
168	Atomic Layer Deposition of InO:H from InCp and HO/O: Microstructure and Isotope Labeling Studies. *ACS Applied Materials & Interfaces*, **2017**, 9, 592-601	9.5	12
167	Electrically conductive coatings consisting of Ag-decorated cellulose nanocrystals. *Cellulose*, **2017**, 24, 2191-2204	5.5	23
166	Synthesis of single-walled carbon nanotubes from atomic-layer-deposited Co3O4 and Co3O4/Fe2O3 catalyst films. *Carbon*, **2017**, 121, 389-398	10.4	12
165	Atomic layer deposition of high-mobility hydrogen-doped zinc oxide. *Solar Energy Materials and Solar Cells*, **2017**, 173, 111-119	6.4	34
164	Dynamic reconfiguration of van der Waals gaps within GeTe-SbTe based superlattices. *Nanoscale*, **2017**, 9, 8774-8780	7.7	57

163	Microscopic studies of polycrystalline nanoparticle growth in free space. *Journal of Crystal Growth*, **2017**, 467, 137-144	1.6	2
162	Improved structural and electrical properties in native Sb2Te3/GexSb2Te3+x van der Waals superlattices due to intermixing mitigation. *APL Materials*, **2017**, 5, 026107	5.7	19
161	Protecting patches in colloidal synthesis of Au semishells. *Chemical Communications*, **2017**, 53, 3898-3901	5.8	4
160	Single-Crystalline Hexagonal Silicon-Germanium. *Nano Letters*, **2017**, 17, 85-90	11.5	45
159	Atomic layer deposition of highly dispersed Pt nanoparticles on a high surface area electrode backbone for electrochemical promotion of catalysis. *Electrochemistry Communications*, **2017**, 84, 40-44	5.1	14
158	(Invited) Area-Selective Atomic Layer Deposition: Role of Surface Chemistry. *ECS Transactions*, **2017**, 80, 39-48	1	9
157	Atomic-layer deposited passivation schemes for c-Si solar cells **2017**,		2
156	Epitaxy of advanced nanowire quantum devices. *Nature*, **2017**, 548, 434-438	50.4	192
155	Effective Surface Passivation of InP Nanowires by Atomic-Layer-Deposited AlO with PO Interlayer. *Nano Letters*, **2017**, 17, 6287-6294	11.5	52
154	Crystal Phase Quantum Well Emission with Digital Control. *Nano Letters*, **2017**, 17, 6062-6068	11.5	23
153	Surface passivation of n-type doped black silicon by atomic-layer-deposited SiO2/Al2O3 stacks. *Applied Physics Letters*, **2017**, 110, 263106	3.4	12
152	The Influence of Particle Size Distribution and Shell Imperfections on the Plasmon Resonance of Au and Ag Nanoshells. *Plasmonics*, **2017**, 12, 929-945	2.4	15
151	High-efficiency humidity-stable planar perovskite solar cells based on atomic layer architecture. *Energy and Environmental Science*, **2017**, 10, 91-100	35.4	184
150	Synthesis of Polystyrene?Polyphenylsiloxane Janus Particles through Colloidal Assembly with Unexpected High Selectivity: Mechanistic Insights and Their Application in the Design of Polystyrene Particles with Multiple Polyphenylsiloxane Patches. *Polymers*, **2017**, 9,	4.5	5
149	Synthesis and Characterization of Hybrid Particles Obtained in a One-Pot Process through Simultaneous Sol-Gel Reaction of (3-Mercaptopropyl)trimethoxysilane and Emulsion Polymerization of Styrene. *Colloids and Interfaces*, **2017**, 1, 7	3	3
148	The competing roles of i-ZnO in Cu(In,Ga)Se2 solar cells. *Solar Energy Materials and Solar Cells*, **2016**, 157, 798-807	6.4	15
147	Influence of growth conditions on the performance of InP nanowire solar cells. *Nanotechnology*, **2016**, 27, 454003	3.4	8
146	Ordered Peierls distortion prevented at growth onset of GeTe ultra-thin films. *Scientific Reports*, **2016**, 6, 32895	4.9	15

145	Revisiting the Local Structure in Ge-Sb-Te based Chalcogenide Superlattices. *Scientific Reports*, **2016**, 6, 22353	4.9	57
144	Surface Infrared Spectroscopy during Low Temperature Growth of Supported Pt Nanoparticles by Atomic Layer Deposition. *Journal of Physical Chemistry C*, **2016**, 120, 750-755	3.8	16
143	Functional nickel-based deposits synthesized by focused beam induced processing. *Nanotechnology* , **2016**, 27, 065303	3.4	7
142	Atomic layer deposition of Pd and Pt nanoparticles for catalysis: on the mechanisms of nanoparticle formation. *Nanotechnology*, **2016**, 27, 034001	3.4	70
141	Nucleation of microcrystalline silicon: on the effect of the substrate surface nature and nano-imprint topography. *Journal Physics D: Applied Physics*, **2016**, 49, 055205	3	1
140	Factors limiting the doping efficiency in atomic layer deposited ZnO:Al thin films: a dopant distribution study by transmission electron microscopy and atom probe tomography **2016**, 888-889		
139	Silicon heterojunction solar cell passivation in combination with nanocrystalline silicon oxide emitters. *Physica Status Solidi (A) Applications and Materials Science*, **2016**, 213, 1932-1936	1.6	9
138	Receptor-Targeted Luminescent Silver Bionanoparticles. *European Journal of Inorganic Chemistry*, **2016**, 2016, 3030-3035	2.3	4
137	Pseudodirect to Direct Compositional Crossover in Wurtzite GaP/InGaP Core-Shell Nanowires. *Nano Letters*, **2016**, 16, 7930-7936	11.5	17
136	Atomic-layer deposited passivation schemes for c-Si solar cells **2016**,		2
135	Atomic stacking and van-der-Waals bonding in GeTeSb2Te3 superlattices. *Journal of Materials Research*, **2016**, 31, 3115-3124	2.5	45
134	On the solid phase crystallization of In2O3:H transparent conductive oxide films prepared by atomic layer deposition. *Journal of Applied Physics*, **2016**, 120, 085314	2.5	20
133	Strong reduction of spectral heterogeneity in gold bipyramids for single-particle and single-molecule plasmon sensing. *Nanotechnology*, **2016**, 27, 024001	3.4	13
132	High-Yield Growth and Characterization of <100> InP p-n Diode Nanowires. *Nano Letters*, **2016**, 16, 3071-7	11.5	11
131	Gas phase grown silicon germanium nanocrystals. *Chemical Physics Letters*, **2016**, 661, 185-190	2.5	2
130	On the Growth, Percolation and Wetting of Silver Thin Films Grown by Atmospheric-Plasma Enhanced Spatial Atomic Layer Deposition. *ECS Transactions*, **2016**, 75, 129-142	1	5
129	Impurity and Defect Monitoring in Hexagonal Si and SiGe Nanocrystals. *ECS Transactions*, **2016**, 75, 751-760	1	5
128	Expanding Thermal Plasma Deposition of Al-Doped ZnO: On the Effect of the Plasma Chemistry on Film Growth Mechanisms. *Plasma Processes and Polymers*, **2016**, 13, 54-69	3.4	4

127	Hexagonal Silicon Realized. *Nano Letters*, **2015**, 15, 5855-60	11.5	118
126	Efficient water reduction with gallium phosphide nanowires. *Nature Communications*, **2015**, 6, 7824	17.4	106
125	Asymmetric magnetic bubble expansion under in-plane field in Pt/Co/Pt: Effect of interface engineering. *Physical Review B*, **2015**, 91,	3.3	87
124	Encapsulation method for atom probe tomography analysis of nanoparticles. *Ultramicroscopy*, **2015**, 159 Pt 2, 420-6	3.1	33
123	Cracking the Si Shell Growth in Hexagonal GaP-Si Core-Shell Nanowires. *Nano Letters*, **2015**, 15, 2974-9	11.5	20
122	Interface formation of two- and three-dimensionally bonded materials in the case of GeTe-Sb□Te□ superlattices. *Nanoscale*, **2015**, 7, 19136-43	7.7	125
121	Correlative transmission electron microscopy and electrical properties study of switchable phase-change random access memory line cells. *Journal of Applied Physics*, **2015**, 117, 064504	2.5	5
120	Highly porous, ultra-low refractive index coatings produced through random packing of silicated cellulose nanocrystals. *Colloids and Surfaces A: Physicochemical and Engineering Aspects*, **2015**, 487, 1-8	5.1	17
119	Exploring Crystal Phase Switching in GaP Nanowires. *Nano Letters*, **2015**, 15, 8062-9	11.5	47
118	Waveguide Nanowire Superconducting Single-Photon Detectors Fabricated on GaAs and the Study of Their Optical Properties. *IEEE Journal of Selected Topics in Quantum Electronics*, **2015**, 21, 1-10	3.8	157
117	p-type nc-SiOx:H emitter layer for silicon heterojunction solar cells grown by rf-PECVD. *Materials Research Society Symposia Proceedings*, **2015**, 1770, 7-12		1
116	Sub-nanometer dimensions control of core/shell nanoparticles prepared by atomic layer deposition. *Nanotechnology*, **2015**, 26, 094002	3.4	55
115	Atomic layer deposition of B-doped ZnO using triisopropyl borate as the boron precursor and comparison with Al-doped ZnO. *Journal of Materials Chemistry C*, **2015**, 3, 3095-3107	7.1	40
114	Nitrogen-doping of bulk and nanotubular TiO2 photocatalysts by plasma-assisted atomic layer deposition. *Applied Surface Science*, **2015**, 330, 476-486	6.7	23
113	Electrocatalytic activity of atomic layer deposited Pt□Ru catalysts onto N-doped carbon nanotubes. *Journal of Catalysis*, **2014**, 311, 481-486	7.3	49
112	Photoelectrochemical hydrogen production on InP nanowire arrays with molybdenum sulfide electrocatalysts. *Nano Letters*, **2014**, 14, 3715-9	11.5	100
111	Atomic Layer Deposition of Highly Transparent Platinum Counter Electrodes for Metal/Polymer Flexible Dye-Sensitized Solar Cells. *Advanced Energy Materials*, **2014**, 4, 1300831	21.8	26
110	Rationally designed single-crystalline nanowire networks. *Advanced Materials*, **2014**, 26, 4875-9	24	55

109	Atomic Layer Deposition of High-Purity Palladium Films from Pd(hfac)2 and H2 and O2 Plasmas. *Journal of Physical Chemistry C*, **2014**, 118, 8702-8711	3.8	52
108	Facile and Versatile Platform Approach for the Synthesis of Submicrometer-Sized Hybrid Particles with Programmable Size, Composition, and Architecture Comprising Organosiloxanes and/or Organosilsesquioxanes. *Chemistry of Materials*, **2014**, 26, 5718-5724	9.6	6
107	Compositional and Structural Analysis of Al-doped ZnO Multilayers by LEAP. *Microscopy and Microanalysis*, **2014**, 20, 526-527	0.5	2
106	Investigation of embedded perovskite nanoparticles for enhanced capacitor permittivities. *ACS Applied Materials & Interfaces*, **2014**, 6, 19737-43	9.5	3
105	Glucose-functionalized polystyrene particles designed for selective deposition of silver on the surface. *RSC Advances*, **2014**, 4, 62878-62881	3.7	17
104	Plasma-Assisted Atomic Layer Deposition of PtOx from (MeCp)PtMe3 and O2 Plasma. *Chemical Vapor Deposition*, **2014**, 20, 258-268		11
103	Rational Design: Rationally Designed Single-Crystalline Nanowire Networks (Adv. Mater. 28/2014). *Advanced Materials*, **2014**, 26, 4908-4908	24	1
102	Reversible switching of InP nanowire growth direction by catalyst engineering. *Nano Letters*, **2013**, 13, 3802-6	11.5	95
101	Electrical transport and Al doping efficiency in nanoscale ZnO films prepared by atomic layer deposition. *Journal of Applied Physics*, **2013**, 114, 024308	2.5	64
100	Formation and electronic properties of InSb nanocrosses. *Nature Nanotechnology*, **2013**, 8, 859-64	28.7	106
99	Efficiency enhancement of InP nanowire solar cells by surface cleaning. *Nano Letters*, **2013**, 13, 4113-7	11.5	119
98	High optical quality single crystal phase wurtzite and zincblende InP nanowires. *Nanotechnology*, **2013**, 24, 115705	3.4	50
97	Room Temperature Sensing of O2 and CO by Atomic Layer Deposition Prepared ZnO Films Coated with Pt Nanoparticles. *ECS Transactions*, **2013**, 58, 203-214	1	3
96	Ultrahigh throughput plasma processing of free standing silicon nanocrystals with lognormal size distribution. *Journal of Applied Physics*, **2013**, 113, 134306	2.5	35
95	Direct band gap wurtzite gallium phosphide nanowires. *Nano Letters*, **2013**, 13, 1559-63	11.5	230
94	Influence of Oxygen Exposure on the Nucleation of Platinum Atomic Layer Deposition: Consequences for Film Growth, Nanopatterning, and Nanoparticle Synthesis. *Chemistry of Materials* , **2013**, 25, 1905-1911	9.6	112
93	Tuning structural motifs and alloying of bulk immiscible Mo-Cu bimetallic nanoparticles by gas-phase synthesis. *Nanoscale*, **2013**, 5, 5375-83	7.7	46
92	Direct-Write Atomic Layer Deposition of High-Quality Pt Nanostructures: Selective Growth Conditions and Seed Layer Requirements. *Journal of Physical Chemistry C*, **2013**, 117, 10788-10798	3.8	53

91	Crystallization Study by Transmission Electron Microscopy of SrTiO3 Thin Films Prepared by Plasma-Assisted ALD. *ECS Transactions*, **2013**, 50, 69-77	1	2
90	Crystallization Study by Transmission Electron Microscopy of SrTiO3Thin Films Prepared by Plasma-Assisted ALD. *ECS Journal of Solid State Science and Technology*, **2013**, 2, N120-N124	2	10
89	ALD of SrTiO3 and Pt for Pt/SrTiO3/Pt MIM Structures: Growth and Crystallization Study. *ECS Transactions*, **2013**, 58, 153-162	1	3
88	Growth and optical properties of axial hybrid III-V/silicon nanowires. *Nature Communications*, **2012**, 3, 1266	17.4	92
87	Improved conductivity of aluminum-doped ZnO: The effect of hydrogen diffusion from a hydrogenated amorphous silicon capping layer. *Journal of Applied Physics*, **2012**, 111, 063715	2.5	9
86	Controlling the resistivity gradient in aluminum-doped zinc oxide grown by plasma-enhanced chemical vapor deposition. *Journal of Applied Physics*, **2012**, 112, 043708	2.5	9
85	Nanostructure□roperty relations for phase-change random access memory (PCRAM) line cells. *Physica Status Solidi (B): Basic Research*, **2012**, 249, 1972-1977	1.3	7
84	Bright single-photon sources in bottom-up tailored nanowires. *Nature Communications*, **2012**, 3, 737	17.4	317
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